

Linear Systems replaces discontinued Siliconix PAD100

The PAD100 is a low leakage Pico-Amp Diode packaged in hermetic TO-72

The PAD100 extremely low-leakage diode provides a superior alternative to conventional diode technology when reverse current (leakage) must be minimized. The PAD100 features a leakage current of -100 pA and is well suited for use in applications such as input protection for operational amplifiers.

PAD100 Benefits:

- Negligible Circuit Leakage Contribution
- Circuit "Transparent" Except to Shunt High-Frequency Spikes
- Simplicity of Operation

PAD100 Applications:

- Op Amp Input Protection
- Multiplexer Overvoltage Protection

FEATURES	
DIRECT REPLACEMENT FOR SILICONIX PAD100	
REVERSE BREAKDOWN VOLTAGE	$BV_R \geq -45V$
ULTRALOW LEAKAGE	$\leq 100 \text{ pA}$
REVERSE CAPACITANCE	$C_{RSS} \leq 2.0\text{pF}$
ABSOLUTE MAXIMUM RATINGS @ 25°C (unless otherwise noted)	
Maximum Temperatures	
Storage Temperature	-65°C to +150°C
Operating Junction Temperature	-55°C to +135°C
Maximum Power Dissipation	
Continuous Power Dissipation	300mW
MAXIMUM CURRENT	
Forward Current (Note 1)	50mA

PAD100 ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTICS	MIN.	TYP.	MAX.	UNITS	CONDITIONS
BV_R	Reverse Breakdown Voltage	-45	--	--	V	$I_R = -1\mu A$
V_F	Forward Voltage	--	0.8	1.5	V	$I_F = 5\text{mA}$
C_{RSS}	Total Reverse Capacitance	--	1.5	2	pF	$V_R = -5V, f = 1\text{MHz}$
I_R	Maximum Reverse Leakage Current	--	--	-100	pA	$V_R = -20V$

Notes:

- Absolute maximum ratings are limiting values above which PAD100 serviceability may be impaired.

Available Packages:

PAD100 in TO-72
PAD100 available as bare die

Please contact Micross for full package and die dimensions



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TO-72 (Bottom View)

